## EVALUATION KIT AVAILABLE Adjustable-Output, Switch-Mode Current Sources with Synchronous Rectifier

### General Description

The MAX1640/MAX1641 CMOS, adjustable-output, switch-mode current sources operate from a +5.5V to +26V input, and are ideal for microprocessor-controlled battery chargers. Charging current, maximum output voltage, and pulse-trickle charge are programmed with external resistors. Programming the off-time modifies the switching frequency, suppressing undesirable harmonics in noise-sensitive circuits. The MAX1640's high-side current sensing allows the load to connect directly to ground, eliminating ground-potential errors. The MAX1641 incorporates a low-side current sense.

The MAX1640/MAX1641 step-down pulse-width-modulation (PWM) controllers use an external P-channel MOSFET switch and an optional, external N-channel MOSFET synchronous rectifier for increased efficiency. An internal low-dropout linear regulator provides power for the internal reference and circuitry as well as the gate drive for the N-channel synchronous rectifier.

The MAX1640/MAX1641 are available in space-saving, 16-pin narrow QSOP packages.

### Applications

Battery-Powered Equipment

Laptop, Notebook, and Palmtop Computers Handy Terminals

Portable Consumer Products

Cordless Phones

Cellular Phones

PCS Phones

Backup Battery Charger



## Pin Configuration

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### \_Features

- ♦ 95% Efficiency
- + +5.5V to +26V Input Supply Range
- 2V to 24V Adjustable-Output Voltage Range
- 100% Maximum Duty Cycle (Low Dropout)
- Up to 500kHz PWM Operation
- Optional Synchronous Rectifier
- 16-Pin QSOP Package
- Current-Sense Accuracy: 2% (MAX1641)
  5.3% (MAX1640)

### \_Ordering Information

| PART       | TEMP. RANGE    | PIN-PACKAGE |
|------------|----------------|-------------|
| MAX1640C/D | 0°C to +70°C   | Dice*       |
| MAX1640EEE | -40°C to +85°C | 16 QSOP     |
| MAX1641C/D | 0°C to +70°C   | Dice*       |
| MAX1641EEE | -40°C to +85°C | 16 QSOP     |

\*Dice are specified at  $T_A = +25$ °C, DC parameters only.

## Typical Operating Circuit



### **ABSOLUTE MAXIMUM RATINGS**

| IN to GND                           | 0.3V to +28V                    |
|-------------------------------------|---------------------------------|
| LDOH to IN                          | +0.3V to -6V                    |
| LDOL to GND                         | 0.3V to +6V                     |
| PDRV to GND (VLDOH - 0.3            | 3V) to (V <sub>IN</sub> + 0.3V) |
| NDRV to GND0.3V                     |                                 |
| TOFF, REF, SET, TERM, CC to GND0.3V | to $(V_{LDOL} + 0.3V)$          |
| D0, D1 to GND                       | 0.3V to +6V                     |
| CS+, CS- to GND                     | 0.3V to +28V                    |

| PGND to GND   | ±0.3V          |
|---|----------------|
| Continuous Power Dissipation ( $T_A = +70^{\circ}C$ ) |                |
| QSOP (derate 8.30mW/°C above +70°C)                   | 667mW          |
| Operating Temperature Range                           |                |
| MAX164_EEE  | 40°C to +85°C  |
| Storage Temperature Range                             | 65°C to +150°C |
| Lead Temperature (soldering, 10sec)                   | +300°C         |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

 $(V_{IN} = +12V, V_{OUT} = 6V, Circuit of Figure 2, T_A = 0^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.)$ 

| PARAMETER  | SYMBOL            | CON  | DITIONS         | MIN                      | ТҮР                      | MAX                      | UNITS |
|--|-------------------|--|-----------------|--------------------------|--------------------------|--------------------------|-------|
| Input Voltage Range  | VIN               |  |                 | 5.5                      |                          | 26                       | V     |
| Linear-Regulator Output<br>Voltage, V <sub>IN</sub> Referenced | V <sub>LDOH</sub> | $V_{IN} = 5.5V$ to 26V, IL                   | OAD = 0 to 20mA | V <sub>IN</sub> -<br>5.5 | V <sub>IN</sub> -<br>5.0 | V <sub>IN</sub> -<br>4.5 | V     |
| Linear-Regulator Output<br>Voltage, Ground Referenced          | VLDOL             | $V_{IN} = 5.5V$ to 26V, IL                   | OAD = 0 to 20mA | 4.5                      | 5.0                      | 5.5                      | V     |
| Full-Scale Current-Sense                                       |                   | MAX1640                                      |                 | 142                      | 150                      | 158                      | mV    |
| Threshold  |                   | MAX1641                                      |                 | 147                      | 150                      | 153                      | IIIV  |
| Quarter-Scale Current-Sense                                    |                   | MAX1640                                      |                 | 36                       | 42                       | 48                       | mV    |
| Threshold  |                   | MAX1641                                      |                 | 34                       | 37.5                     | 41                       | IIIV  |
| Current-Sense Line Regulation                                  |                   | $V_{IN} = V_{OUT} + 0.5V$ to                 | 26V             |                          | 0.03                     |                          | %/V   |
|  |                   | N/   | MAX1640         |                          | 0.1                      | 0.4                      | - %/V |
| Output Current Compliance                                      |                   | $V_{OUT} = 2V \text{ to } 24V$               | MAX1641         |                          | 0.1                      |                          |       |
| Quieceant Mr. Cumply Current                                   |                   | D0 or D1 = high                              |                 |                          | 2                        | 4                        | mA    |
| Quiescent VIN Supply Current                                   |                   | D0 = D1 = low (off mode)                     |                 |                          | 500                      |                          | μA    |
| Output Current in Off Mode                                     |                   | D0 = D1 = Iow                                |                 |                          |                          | 1                        | μA    |
| VLDOL Undervoltage Lockout                                     |                   |  |                 | 4.05                     | 4.20                     | 4.35                     | V     |
| Reference Voltage  | V <sub>REF</sub>  |  |                 | 1.96                     | 2.00                     | 2.04                     | V     |
| Reference Load Regulation                                      |                   | I <sub>REF</sub> = 0 to 50µA                 |                 |                          | 4                        | 10                       | mV    |
| V <sub>SET</sub> Input Current                                 |                   |  |                 |                          |                          | 1                        | μΑ    |
| FET Drive Output Resistance                                    |                   | PFET and NFET drive                          | 9               |                          |                          | 12                       | Ω     |
| Off-Time Range   |                   |  |                 | 1                        |                          | 10                       | μs    |
| Off-Time Accuracy $R_{TOFF} = 62k\Omega$                       |                   |  | 1.7             | 2.2                      | 2.7                      | μs                       |       |
| Pulse-Trickle Mode Duty-Cycle<br>Period                        |                   | D0 = low, D1 = high, $R_{TOFF} = 100k\Omega$ |                 | 27                       | 33                       | 40                       | ms    |
| Pulse-Trickle Mode Duty Cycle<br>(Note 1)                      |                   | D0 = low, D1 = high, $R_{TOFF} = 100k\Omega$ |                 |                          | 12.5                     |                          | %     |

**Note 1:** This ratio is generated by a 1:8 clock divider and is not an error source for current calculations.

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## **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{IN} = +12V, V_{OUT} = 6V, Circuit of Figure 2, T_A = 0^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.)$ 

| PARAMETER              | SYMBOL | CONDITIONS | MIN | ТҮР | MAX | UNITS |
|------------------------|--------|------------|-----|-----|-----|-------|
| PWM Maximum Duty Cycle |        |            | 100 |     |     | %     |
| Input Low Voltage      | VIL    | D0, D1     |     |     | 0.8 | V     |
| Input High Voltage     | VIH    | D0, D1     | 2.4 |     |     | V     |
| Input Leakage Current  | lin    | D0, D1     |     |     | ±1  | μA    |

## **ELECTRICAL CHARACTERISTICS**

(V<sub>IN</sub> = +12V, V<sub>OUT</sub> = 6V, Circuit of Figure 2,  $T_A$  = -40°C to +85°C, unless otherwise noted.)

| PARAMETER  | SYMBOL          | CONDITIONS   | MIN                      | TYP | MAX                      | UNITS |
|--|-----------------|--|--------------------------|-----|--------------------------|-------|
| Input Voltage Range  | VIN             |  | 5.5                      |     | 26                       | V     |
| Linear-Regulator Output<br>Voltage, V <sub>IN</sub> Referenced | VLDOH           | $V_{IN} = 5.5V$ to 26V,<br>I <sub>LOAD</sub> = 0 to 20mA | V <sub>IN</sub> -<br>5.5 |     | V <sub>IN</sub> -<br>4.5 | V     |
| Linear-Regulator Output<br>Voltage, Ground Referenced          | VLDOL           | $V_{IN} = 5.5V$ to 26V,<br>$I_{LOAD} = 0$ to 20mA        | 4.5                      |     | 5.5                      | V     |
| Full-Scale Current-Sense                                       |                 | MAX1640  | 141                      |     | 159                      | mV    |
| Threshold  |                 | MAX1641  | 146                      |     | 154                      |       |
| Quarter-Scale Current-Sense                                    |                 | MAX1640  | 34                       |     | 48                       | mV    |
| Threshold  |                 | MAX1641  | 33                       |     | 42                       |       |
| Output Current Compliance                                      |                 | V <sub>OUT</sub> = 2V to 24V (MAX1640)                   |                          |     | 0.4                      | %/V   |
| Quiescent VIN Supply Current                                   |                 | D0 or D1 = high  |                          |     | 4                        | mA    |
| Output Current in Off Mode                                     |                 | D0 = D1 = low  |                          |     | 1                        | μA    |
| V <sub>LDOL</sub> Undervoltage Lockout                         |                 |  | 4.0                      |     | 4.4                      | V     |
| Reference Voltage  | VREF            |  | 1.94                     |     | 2.06                     | V     |
| Reference Load Regulation                                      |                 | I <sub>REF</sub> = 0 to 50µA                             |                          |     | 10                       | mV    |
| V <sub>SET</sub> Input Current                                 |                 |  |                          |     | 1                        | μA    |
| FET Drive Output Resistance                                    |                 |  |                          |     | 12                       | Ω     |
| Off-Time Range   |                 |  | 1.5                      |     | 8                        | μs    |
| Off-Time Accuracy  |                 | $R_{TOFF} = 62k\Omega$                                   | 1.5                      |     | 2.5                      | μs    |
| Pulse-Trickle Mode Duty-Cycle<br>Period                        |                 | D0 = low, D1 = high, RTOFF = $50k\Omega$                 | 25                       |     | 42                       | ms    |
| PWM Maximum Duty Cycle   |                 |  | 100                      |     |                          | %     |
| Input Low Voltage  | VIL             | D0, D1   |                          |     | 0.8                      | V     |
| Input High Voltage   | VIH             | D0, D1   | 2.4                      |     |                          | V     |
| Input Leakage Current  | l <sub>IN</sub> | D0, D1   |                          |     | ±1                       | μA    |



MAX1640/MAX1641



 $T_{OFF}$  (k $\Omega$ )

INPUT VOLTAGE (V)

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## Typical Operating Characteristics

A: OUTPUT CURRENT, D1 = D0 = 1 1A/div

B: INPUT VOLTAGE, 10V/div

0A

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## Typical Operating Characteristics (continued)

(Circuit of Figure 2,  $T_A = +25^{\circ}C$ , unless otherwise noted.)



A: OUTPUT CURRENT, D0 = D1 = 0 1A/div B: LOAD VOLTAGE, AC coupled, 500mV/div



## \_Pin Description

| PIN  | NAME   | FUNCTION   |
|------|--------|--|
| 1    | LDOL   | Internal, Ground-Referenced Low-Dropout Linear Regulator Output. Bypass with a $0.1\mu$ F capacitor in parallel with a $4.7\mu$ F capacitor to GND.  |
| 2    | TOFF   | Off-Time Select Input. A resistor (R <sub>TOFF</sub> ) connected from this pin to GND programs the off-time for the hysteretic PWM step-down converter. This resistor also sets the period in duty-cycle mode. See <i>Duty-Cycle Mode and Programming the Off-Time</i> . |
| 3, 4 | D1, D0 | Digital Inputs. Select mode of operation (Table 1).  |
| 5    | CC     | Constant-Current Loop Compensation Input. Bypass with a 0.01µF capacitor to GND.   |
| 6    | REF    | Reference Voltage Output ( $V_{REF} = 2V$ ). Bypass with a 0.1µF capacitor to GND.   |
| 7    | SET    | Current Select Input. Program the desired current level by applying a voltage at SET between 0V and $V_{REF}$ , (I = $V_{SET}$ / 13.3 $R_{SENSE}$ ). See Figure 3.   |
| 8    | TERM   | Maximum Output Voltage Termination Input. When V <sub>TERM</sub> exceeds the reference voltage, the comparator resets the internal PWM latch, shutting off the external P-channel FET.   |
| 9    | GND    | Ground   |
| 10   | CS-    | Negative Current-Sense Comparator Input  |
| 11   | CS+    | Positive Current-Sense Comparator Input  |
| 12   | PGND   | High-Current Ground Return for the output drivers  |
| 13   | NDRV   | Gate Drive for an optional N-channel FET synchronous rectifier   |
| 14   | PDRV   | Gate Drive for the P-channel FET   |
| 15   | LDOH   | Internal, Input-Referenced Low-Dropout Linear Regulator Output. Bypass with a $0.33\mu$ F capacitor to IN.   |
| 16   | IN     | Power-Supply Input. Input of the internal, low-dropout linear regulators.  |





Figure 1. MAX1640/MAX1641 Functional Diagram

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MAX1640/MAX1641



Figure 2a. Standard Application Circuit

## \_Detailed Description

The MAX1640/MAX1641 switch-mode current sources utilize a hysteretic, current-mode, step-down pulse-width-modulation (PWM) topology with constant off-time. Internal comparators control the switching mechanism. These comparators monitor the current through a sense resistor (R<sub>SENSE</sub>) and the voltage at TERM. When inductor current reaches the current limit [(VCS+ - VCS-) / RSENSE], the P-channel FET turns off and the N-channel FET synchronous rectifier turns on. Inductor energy is delivered to the load as the current ramps down. This ramp rate depends on R<sub>TOFF</sub> and inductor values. When off-time expires, the P-channel FET turns off.

Two digital inputs, D0 and D1, select between four possible current levels (Table 1). In pulse-trickle mode, the



Figure 2b. Standard Application Circuit

part operates for 12.5% of the period set by R<sub>TOFF</sub>, resulting in a lower current for pulse-trickle charging. Figure 1 is the MAX1640/MAX1641 functional diagram. Figure 2 shows the standard application circuits.

#### Charge Mode: Programming the Output Currents

The sense resistor, RSENSE, sets two charging current levels. Choose between these two levels by holding D0 high, and toggling D1 either high or low (Table 1). The fast-charge current level equals VCS / RSENSE where V<sub>CS</sub> is the full-scale current-sense voltage of 150mV. Alternatively, calculate this current by V<sub>REF</sub> / (13.3RSENSE). The top-off current equals V<sub>SET</sub> / (13.3RSENSE). A resistor-divider from REF to GND programs the voltage at SET (Figure 3).

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The voltage at SET is given by:

R1 = R2 ( $V_{REF} / V_{SET} - 1$ );  $10k\Omega < R2 < 300k\Omega$ 

where  $V_{REF} = 2V$  and  $V_{SET}$  is proportional to the desired output current level.

### Table 1. Selecting Output Current Levels

| •  |    |  |                    |  |  |  |
|----|----|--|--------------------|--|--|--|
| D1 | DO | MODE   | OUTPUT CURRENT (A) |  |  |  |
| 0  | 0  | OFF 0  |                    |  |  |  |
| 0  | 1  | Top-Off V <sub>SET</sub> / (13.3R <sub>SENSE</sub> )                           |                    |  |  |  |
| 1  | 0  | Pulse-Trickle V <sub>SET</sub> / (13.3R <sub>SENSE</sub> )<br>12.5% duty cycle |                    |  |  |  |
| 1  | 1  | Fast Charge V <sub>SET</sub> / (13.3R <sub>SENSE</sub> )                       |                    |  |  |  |







Figure 4a. Setting the Maximum Output Voltage Level



Figure 4b. Setting the Maximum Output Voltage Level

The MAX1640/MAX1641 are specified for V<sub>SET</sub> between 0V and V<sub>REF</sub>. For V<sub>SET</sub> > V<sub>REF</sub>, output current increases linearly (with reduced accuracy) until it clamps at V<sub>SET</sub>  $\approx$  4V.

#### Pulse-Trickle Mode: Selecting the Pulse-Trickle Current

Pulling D0 low and D1 high selects pulse-trickle mode. This current equals  $V_{SET}$  / (13.3R<sub>SENSE</sub>) and remains on for 12.5% of the period set by R<sub>TOFF</sub>. Pulse-trickle current maintains full charge across the battery and can slowly charge a cold battery before fast charging commences.

$$PERIOD = 3.2 \times 10^{-7} \times R_{TOFF}(sec)$$

### Off Mode: Turning Off the Output Current

Pulling D0 and D1 low turns off the P-channel FET and hence the output current flow. This mode also controls end of charge and protects the battery against excessive temperatures.

#### Setting the Maximum Output Voltage Level

The maximum output voltage should be programmed to a level higher than the output/battery voltage (I<sub>LOAD</sub> x R<sub>LOAD</sub>). An external resistor-divider between the output and ground (Figure 4) sets the voltage at TERM. Once the voltage at TERM exceeds the reference, the internal comparator turns off the P-channel FET, terminating current flow. Select R4 in the 10k $\Omega$  to 500k $\Omega$  range. R3 is given by:

where  $V_{TERM} = 2V$  and  $V_{OUT}$  is the desired output voltage.

#### Programming the Off-Time

When programming the off-time, consider such factors as maximum inductor current ripple, maximum output voltage, inductor value, and inductor current rating. The output current ripple is less than the inductor current ripple and depends heavily on the output capacitor's size.

Perform the following steps to program the off-time:

- 1) Select the maximum output current ripple.  $I_R(A)$
- 2) Select the maximum output voltage. V<sub>OUT</sub>(MAX)(V)
- 3) Calculate the inductor value range as follows:

 $L_{MIN} = (V_{OUTMAX} \times 1\mu s) / I_R$ 

 $L_{MAX} = (V_{OUTMAX} \times 10 \mu s) / I_R$ 

- 4) Select an inductor value in this range.
- 5) Calculate toFF as follows:

$$t_{OFF} = \frac{L \times I_R}{V_{OUTMAX}}$$

6) Program toFF by selecting RTOFF from:

 $R_{TOFF} = (29.3 \times 10^9) \times t_{OFF}$ 

7) Calculate the switching frequency by:

$$fs = 1 / (t_{ON} + t_{OFF})$$

where  $t_{ON} = (I_R x L) / (V_{IN} - V_{OUT})$  and  $I_R = (V_{OUT} x t_{OFF}) / L$ . L is the inductor value,  $V_{IN}$  is the input voltage,  $V_{OUT}$  is the output voltage, and  $I_R$  is the output peak-to-peak current ripple.

Note that R<sub>TOFF</sub> sets both the off-time and the pulse-trickle charge period.

#### Reference

The on-chip reference is laser trimmed for a precise 2V at REF. REF can source no more than 50 $\mu$ A. Bypass REF with a 0.1 $\mu$ F capacitor to ground.

#### Constant-Current Loop: AC Loop Compensation

The constant-current loop's output is brought out at CC. To reduce noise due to variations in switching currents, bypass CC with a 1nF to 100nF capacitor to ground. A large capacitor value maintains a constant average output current but slows the loop response to changes in switching current. A small capacitor value speeds up the loop response to changes in switching current, generating increased ripple at the output. Select  $C_{CC}$  to optimize the ripple vs. loop response.

#### Synchronous Rectification

Synchronous rectification reduces conduction losses in the rectifier by shunting the Schottky diode with a lowresistance MOSFET switch. In turn, efficiency increases by about 3% to 5% at heavy loads. To prevent crossconduction or "shoot-through," the synchronous rectifier turns on shortly after the P-channel power MOSFET

### **Table 2. Component Manufacturers**

| COMPONENT      | MANUFACTURER            |                  |  |  |
|----------------|-------------------------|------------------|--|--|
|                | Sumida                  | CDRH125 series   |  |  |
| Inductor       | Coilcraft               | D03316P series   |  |  |
|                | Coiltronics             | UP2 series       |  |  |
| MOSEETS        | International Rectifier | IRF7309          |  |  |
|                | Siliconix               | S14539DY         |  |  |
| Sense Resistor | Dale                    | WSL-2010 series  |  |  |
| Sense Resision | IRC                     | LR2010-01 series |  |  |
| Capacitors     | AVX                     | TPS series       |  |  |
|                | Sprague                 | 595D series      |  |  |
|                | Motorola                | MBAR5340t3       |  |  |
| Rectifier      |                         | IN5817-IN5822    |  |  |
|                | Nihon                   | NSQ03A04         |  |  |

turns off. The synchronous rectifier remains off for 90% of the off-time. In low-cost designs, the synchronous rectifier FET may be replaced by a Schottky diode.

#### **Component Selection**

#### External Switching Transistors

The MAX1640/MAX1641 drive an enhancement-mode P-channel MOSFET and a synchronous-rectifier N-channel MOSFET (Table 2).

When selecting a P-channel FET, some important parameters to consider are on-resistance ( $r_{DS(ON)}$ ), maximum drain-to-source voltage (V<sub>DS</sub> max), maximum gate-to-source voltage (V<sub>GS</sub> max), and minimum threshold voltage (V<sub>TH</sub> min).

In high-current applications, MOSFET package power dissipation often becomes a dominant design factor. I<sup>2</sup>R power losses are the greatest heat contributor for both high-side and low-side MOSFETs. Switching losses affect the upper MOSFET only (P-channel), since the Schottky rectifier or the N-FET body diode clamps the switching node before the synchronous rectifier turns on.

#### **Rectifier Diode**

If an N-channel MOSFET synchronous rectifier is not used, a Schottky rectifier is needed. The MAX1640/





Figure 5. Microcontroller Battery Charger

MAX1641's high switching frequency demands a highspeed rectifier (Table 2). Schottky diodes such as the 1N5817-1N5822 are recommended. Make sure the Schottky diode's average current rating exceeds the peak current limit and that its breakdown voltage exceeds the output voltage (VOUT). For high-temperature applications, Schottky diodes may be inadequate due to their high leakage current; high-speed silicon diodes such as the MUR105 or EC11FS1 can be used instead. At heavy loads and high temperatures, the benefits of a Schottky diode's low forward voltage may outweigh the disadvantage of high leakage current. If the application uses an N-channel MOSFET synchronous rectifier, a parallel Schottky diode is usually unnecessary except with very high charge current (> 3 amps). Best efficiency is achieved with both an N-channel MOSFET and a Schottky diode.

#### Inductor Value

Refer to the section *Programming the Off-Time* to select the proper inductor value. There is a trade-off between

inductor value, off-time, output current ripple, and switching frequency.

### Applications Information

#### All-Purpose Microcontroller Battery Charger: NiCd, NiMH

In applications where a microcontroller is available, the MAX1640/MAX1641 can be used as a low-cost battery charger (Figure 5). The controller takes over fast charge, pulse-trickle charge, charge termination, and other smart functions. By monitoring the output voltage at V<sub>OUT</sub>, the controller initiates fast charge (set D0 and D1 high), terminates fast charge and initiates top-off (set D0 high and D1 low), enters trickle charge (set D0 low and D1 high), or shuts off and terminates current flow (set D0 and D1 low).

#### Layout and Grounding

Due to high current levels and fast switching waveforms, proper PC board layout is essential. High-current ground paths should be connected in a star



configuration to PGND. These traces should be wide to reduce resistance and as short as possible to reduce stray inductance. All low-current ground paths should be connected to GND. Place the input bypass capacitor as close as possible to the IN pin. See MAX1640 EV kit for layout example.

### \_\_Chip Information

TRANSISTOR COUNT: 1233



# Package Information

M/XI/M



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